VISHAY.

DG2730

Vishay Siliconix

2 Port, USB 2.0 High Speed (480 Mbps) Switch, DPDT Analog Switch

DESCRIPTION

The DG2730 is 2 port high speed analog switch optimized for USB 2.0 signal switching. The DG2730 switch is configured in DPDT. It handles bidirectional signal flow, achieving a 900 MHz - 3 dB bandwidth, and a port to port crosstalk and isolation at - 49 dB.

Processed with high density sub micron CMOS, the DG2730 provide low parasitic capacitance. Signals are routed with minimized phase distortion and attain a bit to bit skew is as low as 40 pS.

The DG2730 is designed for a wide range of operating voltages, from 2.7 V to 4.3 V that can be driven directly from one cell Li-ion battery. On-chip circuitry protects against conditions when either the D+/D- lines are shorted to the V_{BUS} at the USB port. Additionally, logic control pins (S and \overline{OE}) can tolerate the presence of voltages that are above the supply power rail (V+). The control logic threshold is guaranteed to be (V_{IH} = 1.3 V/min). Latch up current is 300 mA, as per JESD78, and its ESD tolerance exceeds 8 kV.

Packaged in ultra small miniQFN-10 (1.4 mm x 1.8 mm x 0.55 mm), it is ideal for portable high speed mix signal switching application.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device termination. The miniQFN-10 package has a nickel-palladium-gold device termination and is represented by the lead (Pb)-free "-E4" suffix to the ordering part number. The nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL rating.

As a further sign of Vishay Siliconix's commitment, the DG2730 is fully RoHS complaint.

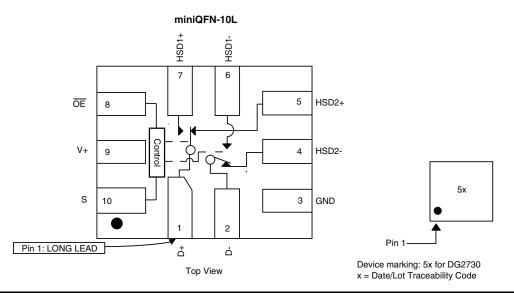
FEATURES

- Halogen-free according to IEC 61249-2-21
 definition
- Wide operation voltage range
- Low on-resistance, 7 Ω (typical at 3 V)
- Low capacitance, 6.5 pF (typical)
- 3 dB high bandwidth: 900 MHz (typical)
- Low bit to bit skew: 40 pS (typical)
- Low power consumption
- Low logic threshold: V
- Power down protection: D+/D- pins can tolerate up to 5 V when V+ = 0 V
- Logic (S and OE) above V+ tolerance
- 8 kV ESD protection (HBM)
- Latch-up current 300 mA per JESD78
- Lead (Pb)-free low profile miniQFN-10 (1.4 mm x 1.8 mm x 0.55 mm)
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Cellular phones
- Portable media players
- PDA
- Digital camera
- GPS
- Notebook computer
- TV, monitor, and set top box

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



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COMPLIANT

HALOGEN

FREE

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ORDERING INFORMAT	ION	
Temp. Range	Package	Part Number
- 40 °C to 85 °C	miniQFN-10	DG2730DN-T1-GE4

TRUTH TABLE						
OE (Pin 8)	S (Pin 10)	Function				
0	1	D+ = HSD1+ and D- = HSD1-				
0	0	D+ = HSD2+ and D- = HSD2-				
1	Х	Disconnect				

PIN DESCRIPTIONS				
Description				
Bus Switch Enable				
Select Input				
Data Port				

Parameter		Limit	Unit	
Reference to GND	V+	- 0.3 to 5	V	
Reference to GND	S, OE, D±, HSD1±, HSD2± ^a	- 0.3 to (V+ + 0.3)	v	
Current (Any Terminal except S, OE, D	±, HSD1±, HSD2±)	30		
Continuous Current (S, OE, D±, HSD1	± 250	mA		
Peak Current (Pulsed at 1 ms, 10 % D	± 500			
Storage Temperature (D Suffix)		- 65 to 150	°C	
Power Dissipation (Packages) ^b	miniQFN-10 ^c	208	mW	
ESD (Human Body Model) I/O to GND		8	kV	
Latch-up (Current Injection)		300	mA	

a. Signals on S, OE, D±, HSD1±, HSD2± exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 2.6 mW/°C above 70 °C.

SPECIFICATIONS (V+ =	= 3 V)						
		Test Conditions		Limits - 40 °C to 85 °C			
Parameter	Symbol			Min. ^b	Typ. ^c	Max. ^b	Unit
Analog Switch							
Analog Signal Range ^d	V _{ANALOG}	R _{DS(on)}	Full	0		V+	V
On-Resistance	Back	V+ = 3 V, I _{D+} = 8 mA, V _{HSD1/2+} = 0.4 V	Room		7	8	Ω
On-nesistance	R _{DS(on)}	$V_{\pm} = 0.0$, $D_{\pm} = 0.000$, $V_{\rm HSD1/2\pm} = 0.000$	Full			9	
On-Resistance Match ^d	ΔR_{ON}	V+ = 3 V, $I_{D\pm}$ = 8 mA, $V_{HSD1/2\pm}$ = 0.4 V	Room		0.8		
On-Resistance Resistance Flatness ^d	R _{ON} Flatness	V+ = 3 V, $I_{D\pm}$ = 8 mA, $V_{HSD1/2\pm}$ = 0 V, 1 V	_{SD1/2±} = 0 V, 1 V Room		2		
Switch Off Leakage Current	I _(off)	V+ = 4.3 V, V _{HSD1/2±} = 0.3 V, 3 V, V _{D±} = 3 V, 0.3 V	Full	- 100		100	
Channel On Leakage Current	I _(on)	V+ = 4.3 V, V _{HSD1/2±} = 0.3 V, 4 V, V _{D±} = 4 V, 0.3 V	Full	- 200		200	nA
Digital Control				•	•	•	
Innut Voltogo Lligh	V	V+ = 3 V to 3.6 V	Full	1.3			
Input Voltage High	V _{INH}	V+ = 4.3 V	Full	Full 1.5			v
Input Voltage Low	V _{INL}	V+ = 3 V to 4.3 V Full			0.5		
Input Capacitance	C _{IN}		Full		6.5		pF
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	- 1		1	μA

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SPECIFICATIONS (V+ =	= 3 V)						
		Test Conditions		Limits - 40 °C to 85 °C			
Parameter	Symbol	Otherwise Unless Specified	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit
Dynamic Characteristics			-	-	-	-	
Break-Before-Make Time ^{e, d}	t _{BBM}		Room Full		5		
Enable Turn-On Time ^{e, d}	t	V+ = 3 V, $V_{D1/2 \pm}$ = 1.5 V, R_L = 50 Ω ,	Room			30	-
Enable Turn-On Time ^{s, a}	t _{ON(EN)}	C _L = 35 pF	Full			25	ns
Enable Turn-Off Time ^{e, d}	t _{OFF(EN)}		Room				
	OFF(EN)		Full			25	
Charge Injection ^d	Q _{INJ}	$C_L = 1 \text{ nF}, R_{GEN} = 0 \Omega, V_{GEN} = 0 V$			0.5		рС
Off-Isolation ^d	OIRR	V+ = 3 V to 3.6 V, R_L = 50 Ω, C_L = 5 pF,			- 30		dB
Crosstalk ^d	X _{TALK}	f = 240 MHz			- 45		
Bandwidth ^d	BW	V+ = 3 V to 3.6 V, R_L = 50 Ω , - 3 dB			900		MHz
al large i d	C _{D1± (off)}		Room		1.3		pF
Channel-Off Capacitance ^d	C _{D2± (off)}				1.3		
	C _{D± (off)}	V+ = 3.3 V, f = 1 MHz			2.7		
Channel-On Capacitance ^d	C _{D± (on)}				6.5		
Channel-to-Channel Skew ^d	t _{SK(O)}				50		
Skew Off Opposite Transitions of the Same Output ^d	t _{SK(p)}	V+ = 3 V to 3.6 V, R _L = 50 Ω , C _L = 5 pF			20		ps
Total Jitter ^d	tj				200		
Power Supply							
Power Supply Range	V+			2.6		4.3	V
Power Supply Current	l+	$V_{IN} = 0 V$, or V+	Full			2	μA

Notes:

a. Room = 25 $^{\circ}$ C, Full = as determined by the operating suffix.

b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.

c. Typical values are for design aid only, not guaranteed nor subject to production testing.

d. Guarantee by design, not subjected to production test.

e. V_{IN} = input voltage to perform proper function.

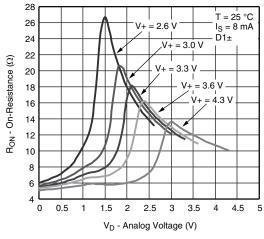
f. Crosstalk measured between channels.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

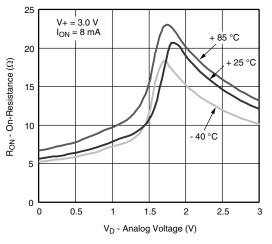


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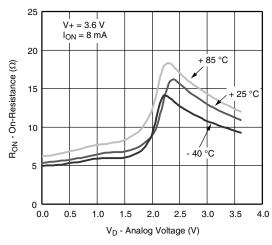
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



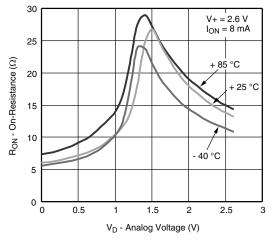
 \mathbf{R}_{ON} vs. \mathbf{V}_{D} and Single Supply Voltage



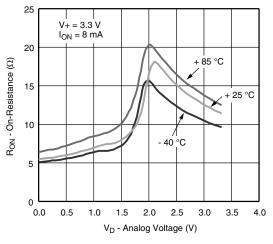
R_{ON} vs. Analog Voltage and Temperature



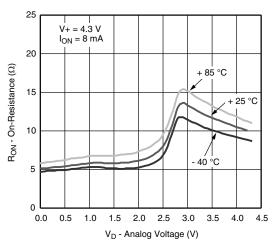
R_{ON} vs. Analog Voltage and Temperature



R_{ON} vs. Analog Voltage and Temperature



R_{ON} vs. Analog Voltage and Temperature

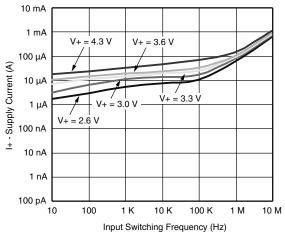


R_{ON} vs. Analog Voltage and Temperature

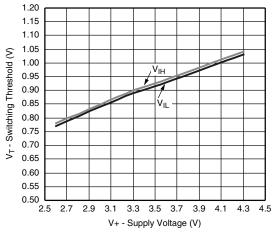
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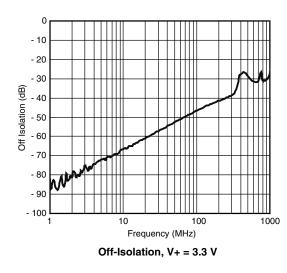
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

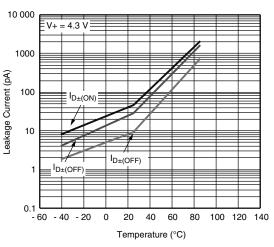


Supply Current vs. Input Switching Frequency

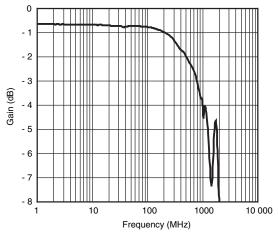


Switching Threshold vs. Supply Voltage

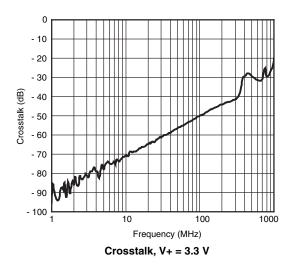




Leakage Current vs. Temperature



Gain vs. Frequency, V+ = 3.3 V



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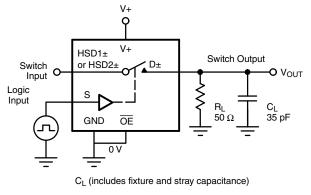
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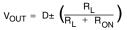
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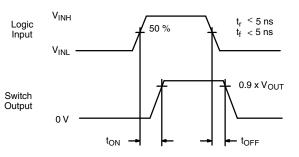
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TEST CIRCUITS

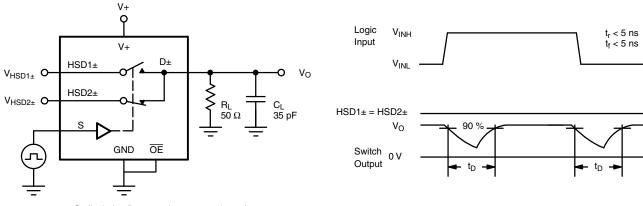






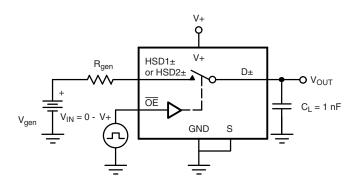
Logic "1" = Switch on Logic input waveforms inverted for switches that have the opposite logic sense.

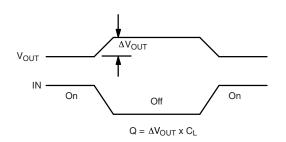




C_L (includes fixture and stray capacitance)







IN depends on switch configuration: input polarity determined by sense of switch.



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TEST CIRCUITS

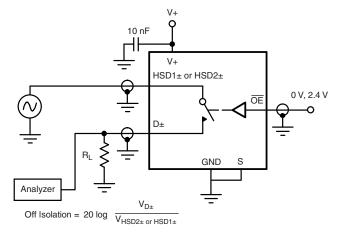


Figure 4. Off-Isolation

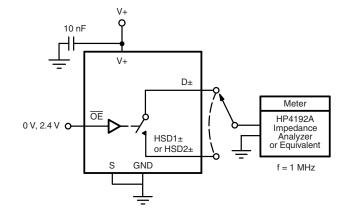
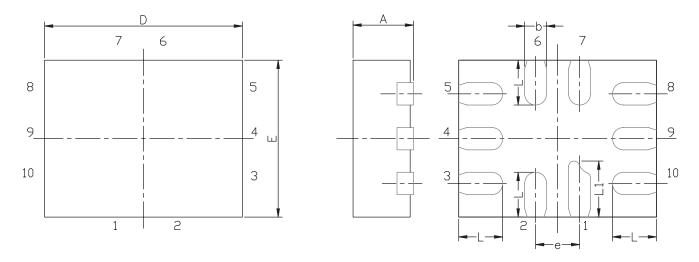


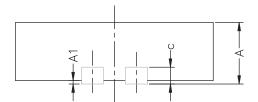
Figure 5. Channel Off/On Capacitance

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MINI QFN-10L CASE OUTLINE





DIM	MILLIMETERS			INCHES			
DIN	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.	
А	0.50	0.55	0.60	0.0197	0.0217	0.0236	
A1	0.00	-	0.05	0.000	-	0.002	
b	0.15	0.20	0.25	0.006	0.008 0.010		
с	0.15 REF			0.006 REF			
D	1.75	1.80	1.85	0.069	0.071 0.073		
E	1.35	1.40	1.45	0.053	0.055	0.057	
е	0.40 BSC			0.016 BSC			
L	0.35	0.40	0.45	0.014	0.016	0.018	
L1	0.45	0.50	0.55	0.0177	0.0197	0.0217	

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DWG: 5957



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